

## COMBINED DECLARATION AND POWER OF ATTORNEY FOR UTILITY PATENT APPLICATION

Attorney's Docket No.

030681-344

As a below-named inventor, I hereby declare that: My residence, post office address and citizenship are as st I BELIEVE I AM THE ORIGINAL, FIRST AND SOL ORIGINAL, FIRST AND JOINT INVENTOR (if more the WHICH IS CLAIMED AND FOR WHICH A PATENT	LE INVI han one IS SOU	ENTOR (if only one name is listed below) OR AN : name is listed below) OF THE SUBJECT MATTER; GHT ON THE INVENTION ENTITLED:
GAN BASED GROUP III-V NITRIDE SEMICONDUC	CIOR L	IGHT-EMITTING DIODE AND METHOD FOR
FABRICATING THE SAME		
the specification of which		
(check one)	×	is attached hereto:
(Check Ville)		was filed on as
	Anni	ication No.
	31143 /	vas amended on; (if applicable)
I HAVE REVIEWED AND UNDERSTAND THE CON- INCLUDING THE CLAIMS, AS AMENDED BY ANY I ACKNOWLEDGE THE DUTY TO DISCLOSE TO THE MATERIAL TO PATENTABILITY AS DEFINED IN TO (as amended effective March 16, 1992);	AMENI	OMENT REFERRED TO ABOVE:  CE ALL INFORMATION KNOWN TO ME TO BE
I do not know and do not believe the said invention was my or our invention thereof, or patented or described in invention thereof or more than one year prior to said applie the United States of America more than one year prior to a made the subject of an inventor's certificate issued before United States of America on any application filed by in months prior to said application.	n any pi cation: t said app e the da	rinted publication in any country before my or our hat said invention was not in public use or on sale in lication; that said invention has not been patented or use of said application in any country to eight to the
I hereby claim foreign priority benefits under Title 35, Unapplication(s) for patent or inventor's certificate as indusplication for patent or inventor's certificate on this inventible priority is claimed:	licated 1	below and have also identified below any foreign

				Attorney's Docket No.			
COMBINED DECLARATION AND POWER OF ATTORI			VEY	IEY			
					030681-344		
COUNTRY/INTERNA	TIONAL	APPLICATION NUMBER		DATE OF FILING (day, month, year)		PRIORITY CLAIMED	
Rep. of Korea		2000-77746		18 Dec	cember 2000	YESK NO_	
Rep. of Korea		2001-4035		29 Jai	nuary 2001	YESX NO_	
I hereby appoint the following attorneys and agent(s) to prosecute said application and to transact all business in the Patent and Trademark Office connected therewith and to file, prosecute and to transact all business in connection with international applications directed to said invention:							
William L. Mathis Peter H. Smolka Robert S. Swecker Platon N. Mandros Benton S. Duffett, Jr. Joseph R. Magnone Norman H. Stepno Ronald L. Grudziecki Frederick G. Michaud, Jr. Alan E. Kopecki Regis E. Slutter	17,337 15,913 19.885 22,124 22,030 24,239 22,716 24,970 26,003 25,813 26,999	Samuel C. Miller, Raiph L. Freeland Robert G. Mukai George A. Hovane James A. LaBarre E. Joseph Gess R. Danny Hunting Eric H. Weisblatt James W. Petersor Teresa Stanck Rea Robert E. Krebs	, Jr. 16,1 28,5 50, Jr. 28,2 28,6 28,5 ton 27,9 30,5 a 26,0	10 31 223 32 10 23 25 57 27	Robert M. Schult William C. Rowle T. Gene Dillahun Patrick C. Keane Bruce J. Boggs, J William H. Benz Peter K. Skiff Richard J. McGra Maithew L. Schn Michael G. Savag Gerald F. Swiss Charles F. Wiclas	and 30,888 ty 25,423 32,858 Ir. 32,344 25,952 31,917 ath 29,195 eider 32,814 te 32,596 30,113	
and:							
Address all correspondence to:  Charles F. Wieland III  BURNS, DOANE, SWECKER & MATHIS, L.L.P.  P.O. Box 1404  Alexandria, Virginia 22313-1404							
Address all telephone calls	to: Charle	s F. Wieland III				_ at (703) 836-6620.	
I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.							
FULL NAME OF SOLE OR FIR	ST INVENTOR		SIGNATURE	h 11.	1	DATE	
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Suron-city, Kyungki-do, Rep. of Korea  FULL NAME OF FIFTH JOINT INVENTOR, IF ANY SIGNATURE DATE						
FULL NAME OF FIFTH JOINT INVENTOR, IF ANY	SIGNATURE	<del></del>	DATE			
RESIDENCE	•	CITIZENSHIP	7.			
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FULL NAME OF SIXTH JOINT INVENTOR, IF ANY						
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FULL NAME OF SEVENTH JOINT INVENTOR, IF ANY	SIGNATURE		DATE			
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full name of eighth joint inventor, if any	SIGNATURE		DATE			
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FULL NAME OF NINTH JOINT INVENTOR, IF ANY						
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FULL NAME OF ELEVENTH JOINT INVENTOR, IF ANY	SIGNATURE		DATE			
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FULL NAME OF TWELFTH JOINT INVENTOR, IF ANY	SIGNATURE		DATE			
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